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TABLE OF CONTENTS

FinFET: From Compact Modeling to Circuit Performance	1
<i>Frank He, Xingye Zhou, Chenyue Ma, Jian Zhang, Zhiwei Liu, Wen Wu, Xukai Zhang, Lining Zhang</i>	
Variability Investigation of Gate-All-Around Silicon Nanowire Transistors from Top-Down Approach	7
<i>R. Huang, R. S. Wang, J. Zhuge, T. Yu, Y. J. Ai, C. Fan, S. S. Pu, J. B.Zou, X. Huang, Y. Y. Wang</i>	
Heterogeneous Integration of DC-DC Power Converters	11
<i>Krishna Shenai</i>	
A Sub-1V Voltage-Mode DC-DC Buck Converter Using PWM Control Technique	19
<i>Ming-Xiang Lu, Bo-Han Hwang, Jiann-Jong Chen, Yuh-Shyan Hwang</i>	
Voltage Mode Control of Coupled Inductor Bidirectional DC to DC Converter	23
<i>B. L. Narasimharaju, S. P. Dubey, S. P. Singh</i>	
Investigating the Global Trend of Semiconductor Industry by Reviewing the Digital-Analog Converters	29
<i>Bing Han, Akira Matsuzawa, Jianguo Ma</i>	
A 14-bit 5MHz Continuous-time Sigma-delta ADC.....	35
<i>Gao Jing,Tu Mingqiang, Luo Tao</i>	
Analysis and Optimization of Mismatch and Parasitics in Pipelined ADCs.....	39
<i>Yu Wang, Hai-gang Yang, Xin Cheng, Tao Yin</i>	
Advanced Multi-High-Operation-Voltage I/O Device Design for 32nm Gate-First HiK MG Technology	43
<i>Xusheng WU, Y. Hu, N. Kusunoki, Z. J. Yang, G. Yang, Y. Teh, R. Kirshnan, S. Krishnan, J. Shepard, S. Han, Y. Lee, F. Arnaud, M. Sherony, J. Sudijono, A. Steegen</i>	
Electrical Characteristics of Al-doped ZnO-channel Thinfiln Transistor with High-K HfON/SiO₂ Stack Gate Dielectric	47
<i>Xiao Zou, J. P. Xu, P. T. Lai, Yao Li, Feng Ji, L. F. Deng</i>	
Improved Performance of Low-Voltage Pentacene OTFTs by Incorporating La to Hafnium Oxide Gate Dielectric.....	51
<i>L. F. Deng, P. T. Lai, Q. B. Tao, H. W. Choi, J. P. Xu, W. B. Chen, C. M. Che, Y. R. Liu</i>	
Varying Sputtering Ambient and Annealing Gas to Optimize the Electrical Properties of MOS Capacitor with HfLaO Gate Dielectric	55
<i>Q. B. Tao, P. T. Lai</i>	
Audio Susceptibility Aware Ramp Signal Design on Feedforward Voltage-Mode CCM Buck Converter.....	59
<i>Edward N. Y. Ho, Philip K. T. Mok</i>	
Output-Capacitor-Free Adaptively Biased Low-Dropout Regulators	63
<i>Chenchang Zhan, Wing-Hung Ki</i>	
A Fast-Transient LDO Based on Buffered Flipped Voltage Follower.....	67
<i>Hua Chen, Ka Nang Leung</i>	
Soft-Start Circuit with Duty Ratio Controlled Voltage Clamping and Adaptive Sizing Technique for Integrated DC-DC Converters.....	71
<i>Xiaocheng Jing, Philip K. T. Mok</i>	
A Low-voltage Charge Pump with Wide Current Driving Capability.....	75
<i>Oi-Ying Wong, Wing-Shan Tam, Chi-Wah Kok, Hei Wong</i>	
A MEMS-Based Flexible Electrode Array Using Composite Substrate.....	79
<i>Tian-Ling Ren, Bing Yan, Jian-Hui Lin, Xiao-Ming Wu, Li-Gang Wang, Yi Yang, Li-Tian Liu</i>	
Integrating Carbon-Based Nanoelectronics with Chalcogenide Phase Change Memory	85
<i>Feng Xiong, Albert Liao, Myung-Ho Bae, David Estrada, Eric Pop</i>	
WZ-GaN based Quasi-Read ATT Diode: A Novel High-Power THz Device with Reduced Parasitic Resistance	89
<i>Moumita Mukherjee</i>	
Design and Optimization of A Novel SOI LDMOS Structure Using PIN Junction	93
<i>Mingda Zhu, Juncheng Wang, Gang Du</i>	
RESET Modeling of PCM using Thermal Budget Approach	97
<i>K. C. Kwong, Jin He, Philip K. T. Mok, Mansun Chan</i>	
A Simple Physically Based Model of Temperature Effect on Drain Current for Nanoscale TFET.....	101
<i>Omor Faruk Shoron, Saima Afroz Siddiqui, Ahmad Zubair, Q. D. M. Khosru</i>	

Modeling of Current Gain versus Recombination in Double Base Epilayer 4H-SiC BJTs	105
<i>Qian Zhang, Yuming Zhang, Yimen Zhang, Yuehu Wang</i>	
Magnetic Coupling Calculations Using Partial Inductance Theory	108
<i>Y. Zhang, N. H. W. Fong, A. H. W. Choi, N. Wong</i>	
Double Edge-Triggered Half-Static Clock-Gated D-Type Flip-Flop.....	112
<i>Wing-Shan Tam, Sik-Lam Siu, Chi-Wah Kok, Hei Wong</i>	
A 4.5-GHz 256~511 Multi-Modulus Frequency Divider Based on Phase Switching Technique for Frequency Synthesizers.....	116
<i>Wenguan Li, Honglin Chen, Lei Shi</i>	
A High-Resolution All-Digital Duty-Cycle Corrector with a New Pulse-Width Detector	120
<i>Ji-Wei Ke, Shi-Yu Huang, Ding-Ming Kwai</i>	
A Serial Physical Layer Design in RapidIO	124
<i>Wu Fengfeng, Jia Song, Li Wujian, Wang Yuan</i>	
Low-Power High-Speed Multiplier for Error-Tolerant Application.....	128
<i>Khaing Yin Kyaw, Wang Ling Goh, Kiat Seng Yeo</i>	
Design of Low Power ASK CMOS Demodulator Circuit for RFID Tag: Design of All-MOSFET Low Power ASK Demodulator.....	132
<i>Myoeng-Jae Choi, Sung-Eon Jin</i>	
A Single-PLL UWB Frequency Synthesizer using Current Reusing SSB Mixer	136
<i>Wei Li, K. K. M. CHENG</i>	
2.4 GHz GaAs PHEMT Medium Power Amplifier for Wireless LAN Applications.....	140
<i>Amiza Rasmi, M. Rafie Che Rose, Ahmad Ismat, Abdul Rahim, Arjuna Marzuki</i>	
3-Stage 15 GHz p-HEMT Power Amplifier Design for MMIC Applications	144
<i>S. Rasidah, Amiza Rasmi, M. H. Siti Maisurah, A. I. A. Rahim, M. R. Yahya</i>	
A Dual Band CMOS Receiver with Hybrid Down Conversion Mixer for IEEE 802.11a/b/g/n WLAN Applications.....	148
<i>Dong-Ok Han, Jeong-Hoon Kim, Sang-Gy Park</i>	
Improvements of Fermi-level Pinning and NBTI by Fluorinated HfO₂-CMOS.....	152
<i>Chao-Sung Lai, Woei-Cherng Wu, Huai-Hsien Chiu, Jer-chyi Wang, Pai-Chi Chou, Tien-Sheng Chao</i>	
Bipolar Switching Analysis and Negative Resistance Phenomenon in TiO_x-based Devices	156
<i>Linkai Wang, Ze Jia, Tianling Ren</i>	
Electrical Properties of HfTiO Gate-dielectric Metal Oxide Semiconductor Capacitors with NO and N₂O Surface Nitridations	159
<i>F. Ji, J. P. Xu, C. X. Li, P. T. Lai, L. F. Deng, X. Zou</i>	
Electrode Effects on the Breakdown Characteristics of High-k HfO₂ Metal-Insulator-Metal Capacitors	163
<i>W. M. Tang, M. G. Helander, M. T. Greiner, W. T. Ng, Z. H. Lu</i>	
Short Locking Time Phase-locked Loop Based on Adaptive Bandwidth Control.....	167
<i>Zhongjie Guo, Longsheng Wu, Youbao Liu</i>	
Fast Locking PLL with All-digital Locked-aid Circuit	171
<i>Fu-Jen Hsieh, Shao-Ku Kao</i>	
A Wideband Colpitts VCO with 30% Continuous Frequency Tuning Range Using a Tunable Phase Shifter	175
<i>Ying Chen, Koen Mouthaan, Marcel Geurts</i>	
A Time-to-Digital Converter Using a Multi-Phase Voltage-Controlled Oscillator	179
<i>I-Fu Tang, Shao-Ku Kao</i>	
Design of a 24GHz Wide Tuning-Range VCO with Optimized Switches in Resonator.....	182
<i>Hongda Zheng, Dongxu Yang, Dajie Zeng, Li Zhang, Zhiping Yu</i>	
Field-Plate Technique for High Power Compound Semiconductor Devices Applications	186
<i>HSIEN-CHIN CHIU, CHAO-WEI LIN, CHE-KAI LIN</i>	
GaN Schottky Barrier MOSFET using Indium-Tin-Oxide as Source, Drain and Gate Material	190
<i>Tae-Hyeon Kim, Byung-Kwon Jung, Chang-Ju Lee, Dong-Seok Kim, Sang-Yun Sung, Young-Woo Heo, Jung-Hee Lee, Sung-Ho Hahm</i>	
Body Bias Effect of GaN Schottky Barrier MOSFET with ITO Source/Drain.....	194
<i>Chang-Ju Lee, Tae-Hyeon Kim, Dong-Seok Kim, Sang-Yun Sung, Byung-Kwon Jung, Young-Woo Heo, Jung-Hee Lee, Sung-Ho Hahm</i>	
A Large-signal Model for GaInP/GaAs Heterojunction Bipolar Transistors.....	198
<i>Yuxia Shi, Yu He, Lin Wang, Yan Wang</i>	
Unveiling Switching Mechanisms in RRAMs.....	202
<i>Zhiping Yu, Yan Wang</i>	

An Access-Transistor-Free Resistive Random Access Memory (RRAM) Using a GST/TiO₂ Stack and Its Novel Access Mechanism	206
<i>Jeong-Hoon Oh, Kyung-Chang Ryoo, Sunghun Jung, Byung-Gook Park, Kyung Seok Oh</i>	
Ground Plane SOI MOSFET Based SRAM With Consideration of Process Variation	210
<i>Mehdi Saremi, Behzad Ebrahimi, Ali Afzali-Kusha</i>	
A Compact Model of Diode Array for Phase Change Memory	214
<i>Yanmei Su, Laidong Wang, Ruonan Wang, Xukai Zhang, Yiqun Wei, Wei Wang, Yong Ma, Xinnan Lin, Jin He</i>	
A CAD Tool for Design and Analysis of CNFET Circuits.....	218
<i>Jiale Huang, Minhao Zhu, Pallav Gupta, Shengqi Yang, Steven M. Rubin, Gilda Garret, Jin He</i>	
CMOS Digitally Programmable Lossless Floating Inductor.....	222
<i>Lobna A. Said, Ahmed H. Madian, Mahmoud H. Isamil, Ahmed M. Soliman</i>	
An Adaptive Edge Enhancement Algorithm and Hardware Implementation.....	226
<i>Jinkai Long, Xiaoxin Cui, Dunshan Yu</i>	
Total Ionizing Dose Effects on 4-Transistor CMOS Image Sensor Pixels.....	229
<i>Jiaming Tan, Albert J. P. Theuwissen</i>	
A Low Power All-Digital PLL with Power Optimized Digitally Controlled Oscillator	233
<i>Doo-Chan Lee, Kyu-Young Kim, Young-Jae Min, Kyung-Min Kim, Ammar Abdullah, Jongsun Park, Soo-Won Kim</i>	
New CMOS Inverter-Based Voltage Multipliers	237
<i>Ho-Cheng Lin, Dong-Shiuh Wu, Che-Min Kung, Yuh-Shyan Hwang, Jiann-Jong Chen</i>	
A 3.0-5.0 GHz High Linearity and Low Power CMOS Up-Conversion Mixer for UWB Applications	241
<i>S. A. Z. Murad, R. K. Pokharel, H. Kanaya, K. Yoshida</i>	
A New Integrated Low-Power BPSK Demodulator for Wireless Implantable Neural Recording System.....	245
<i>C. P. Li, Z. H. Wu, B. Li</i>	
2 - 13GHz Broadband CMOS Low Voltage Mixer with Active Balun Designed for UWB Systems.....	249
<i>I-Chuan Chen, Jeng-Rern Yang</i>	
Phase Change Materials and Random Access Memory	253
<i>Zhitang Song, Feng Rao, Yun Ling, Liangcai Wu, Bo Liu</i>	
Comparative Study of High-k HfLaON and HfON as Charge-Storage Layer of MONOS Memory	257
<i>L. Liu, J. P. Xu, X. D. Huang, F. Ji, P. T. Lai</i>	
YAlO_x as Inter-Poly Dielectric for Improved Performance of Flash-Memory Application	261
<i>X. D. Huang, P. T. Lai</i>	
Analytical Modeling of Read Stability Metric of SRAM Cell in Nanoscale era	265
<i>Behzad Ebrahimi, Hossein Aghababa, Ali Afzali-Kusha</i>	
A End-Point Prediction Scheme with Constant Amplitude Ramp Signal Suitable for High Voltage Applications.....	269
<i>Min Tan, Qianneng Zhou</i>	
CMOS Precision Full-Wave Rectifier Using Current Conveyor	273
<i>Montree Kumngern</i>	
High-Conversion-Ratio Buck Regulator for SoC in 0.13µm Digital CMOS Process	277
<i>Jiana Lou, Yueming Sun, Xiaobo Wu, Menglian Zhao</i>	
Modelling and Stability Analysis of Coupled Inductor Bidirectional DC-DC Converter.....	281
<i>B. L. Narasimharaju, S. P. Dubey, S. P. Singh</i>	
High Efficiency LED Driver Featuring Auto Output-Voltage Tuning.....	286
<i>Yue-Ming Sun, Xiao-Bo Wu</i>	
Performance Analysis of Pixelated Source-mask Optimization for Optical Microlithography	290
<i>Ningning Jia, Edmund Y. Lam</i>	
A High Breakdown Voltage and Low Switching Loss GaN Schottky Diode Using CHF₃ Plasma Treatment.....	294
<i>Sheng -Wen Peng, Chih-Wei Yang, Chao-Hung Cheng, Che-Kai Lin, Hsien-Chin Chiu</i>	
Analytical Subthreshold Channel Potential Model of Asymmetric Gate Underlap Gate-all-around MOSFET	297
<i>Shaodi Wang, Xinjie Guo, Lining Zhang, Chenfei Zhang, Frank He, Mansun Chan</i>	
Effect of Single HALO Doped Channel in Tunnel FETs: A 2-D Modeling Study.....	301
<i>Binit Syamal, Chayanika Bose, C. K. Sarkar, N. Mohankumar</i>	
Submicron MILC TFT Performance Enhancement by Crystallization after Patterning	305
<i>Lin Li, Mansun Chan</i>	
4H-SiC Junction Barrier Schottky Diode with Embedded P-Layer.....	309
<i>Yimen Zhang, Yuming Zhang, Xiaoyan Tang, Yuehu Wang, Renxu Jia, Qingwen Song, Fengping Chen</i>	
RDF Effect Induced by Source/Drain Doping in Nano-Scale UTB SOI MOSFET with Nominally Un-doped Channel	314
<i>Linfeng Du, Shengdong Zhang</i>	

Influence of Collector Region Design on SiGe Power HBT Linearity Characteristics	318
<i>Guoxuan Qin, Jianguo Ma, Guogong Wang, Zhenqiang Ma, Pingxi Ma, Marco Racanelli</i>	
Effect of Majority Carrier Current on the Base Transit Time of a BJT for Exponential Doping	322
<i>M. M. Shahidul Hassan, Md. Iqbal Bahar Chowdhury</i>	
Feedthrough Cancellation in Micromechanical Square Resonators via Differential Transduction	326
<i>Yuanjie XU, Joshua E. Y. Lee</i>	
A 0.5V Amplifier with Adaptive CMFB Compensation for a 2-1 Cascade CT Delta Sigma Modulator	330
<i>Yan Chen, Xiao-yong He, Kong-pang Pun</i>	
Analysis on Panel Power Consumption of Mobile TFT-LCDs Based on Line Inversion Driving	334
<i>Jae-Hyuck Woo, Bai-Sun Kong, Jae-Goo Lee, Gyoo-Cheol Hwang, Myung-Hee Lee, Young-Hyun Jun</i>	
Improved Multi-loop SMASH Sigma-Delta Modulator for Wideband Applications	338
<i>Hongyi Li, Yuan Wang, Song Jia, Xing Zhang</i>	
Design and Analysis of Low-Voltage Silicon-Controlled Rectifier ESD Protection Circuit	342
<i>Zitao Shi, Jian Liu, Xin Wang, Lin Lin, Albert Wang, Yuhua Cheng, Li-Wu Yang</i>	
Miniaturized Microwave Bandpass Filter Based on Modified Hairpin Topology	346
<i>K. Srisathit, J. Tangjit, W. Surakampontorn</i>	
The Variations of Oscillation Frequency According to the Oscillation Amplitudes in DCO	350
<i>Sang-Sun Yoo, Jeong-Ho Park, Hong-Joo Song, Hyung-Joun Yoo</i>	
Electronically Tunable Current-Mode Multiphase Oscillator Using Current-Controlled CCTAs	354
<i>Montree Kunngern</i>	
A Clock and Data Recovery Circuit for 3.125Gb/s RapidIO SerDes	358
<i>Zhao Zhihui, Wang Yuan, Zhao Junlei, Yang Hailing, Jia Song</i>	
Investigating A Novel CMOS Ring Oscillator With LC-Feedbacks	362
<i>Tan Lu, Weijie Zhu, Wanjing Zhu, Jianguo Ma</i>	
Frequency Multiplier Design Using BiCMOS-Based Multiple-Peak NDR Circuit	366
<i>Kwang-Jow Gan, Ping-Feng Wu, Wu-Yan Shie, Cher-Shiung Tsai, Dong-Shong Liang, Cheng-Hsiung Tsai, Wen-Kuan Yeh</i>	
Statistical Analysis for the Oscillation Frequency of a Ring Oscillator	369
<i>Wanjing Zhu, Tan Lu, Weijie Zhu, Jianguo Ma</i>	
Joint-PDF of Timing and Power of Nano-scaled CMOS Digital Gates due to Channel Length Variation	373
<i>Seyed-Nima Mozaffari, Hossein Aghababa, Ali Afzali-Kusha</i>	
Characteristics of Subband Current Ratio in Double-Gate MOSFET	377
<i>Haijun Lou, Xinnan Lin, Lining Zhang, Xukai Zhang, Jiaojiao Xu, Wen Wu, Zhiwei Liu, Wenping Wang, Wei Zhao, Yong Ma, Frank He, Mansun Chan</i>	
Design of Complementary GAA-NW Tunneling-FETs of Axial Si-Ge Heterostructure	381
<i>Shengxi Huang, Ximeng Guan, Jinyu Zhang, Victor Moroz, Yan Wang, Zhiping Yu</i>	
A Magnetically Shielded Instrument for Magnetoresistance and Noise Characterizations of Magnetic Tunnel Junction Sensors	385
<i>Z. Q. Lei, G. J. Li, P. T. Lai, Philip W. T. Pong, William. F. Egelhoff Jr.</i>	
A Study on Hydrogen Adsorption of Metal-Insulator-Silicon Sensor with La₂O₃ as Gate Insulator	389
<i>Gang Chen, P. T. Lai, Jerry Yu</i>	
Indirect Compensation Technique based Two-Stage Recycling Folded Cascode Amplifier for Reconfigurable Multi-Mode Sigma-Delta ADC	393
<i>Ghazal. A. Fahmy, R. K. Pokharel, H. Kanaya, K. Yoshida</i>	
Slew-Rate Enhancement Circuit of CMOS Current-Mirror Amplifier by Edge-Detecting Technique	397
<i>Ka Yee Kwong, Ka Nang Leung</i>	
Low Gain-Error Instrumentation Amplifier for Current Sensing	401
<i>Jiongming Wang, Fuding Ge, Shengqi Yang, Xinnan Lin, Jin He</i>	
A Low Noise Charge Sensitive Amplifier with Adjustable Leakage Compensation in 0.18μm CMOS process	405
<i>Xiangyu LI, Qi ZHANG, Yihe SUN</i>	
A CMOS Inverter-Based Class-AB Pseudo Differential Amplifier for HF Applications	409
<i>Apirak Suadet, Varakorn Kasemsuwan</i>	
A Simple Compact Model for Hot Carrier Injection Phenomenon in 32 nm NAND Flash Memory Device	413
<i>Myounggon Kang, Wookgee Hahn, Il Han Park, Hocheol Lee, Juyoung Park, Youngsun Song, Changgyu Eun, Sanghyun Ju, Kihwan Choi, Youngho Lim, Jong-Ho Lee, Byung-Gook Park, Hyungcheol Shin</i>	
Two-Dimensional Quantum Mechanical Simulation of Gate Leakage Current of Nanoscale MOSFETs	417
<i>Hao Wang, Gaofeng Wang, Sheng Chang</i>	

A Model for Ovonic Threshold Switch of Amorphous GST Based on Hopping Transport Process	421
<i>Wei Wang, Xinnan Lin, Yiqun Wei, Laidong Wang, Ling Wang, Jin He, Xing Zhang</i>	
The Impact of Device Parameter Variation on Double Gate Tunneling FET and Double Gate MOSFET	425
<i>Lining Zhang, Mansun Chan, Frank He</i>	
Modeling of Flicker Noise in n-Channel FinFETs : Mobility Fluctuations in the Subthreshold Region.....	429
<i>Srabanti Pandit, Binit Syamal, C. K. Sarkar</i>	
Implementation of HF Multi-standard RFID Transceiver for Compact Mobile Devices.....	433
<i>Hong-Joo Song, Sang-Sun Yoo, Hyung-Joun Yoo</i>	
Multilayer Asymmetrical Compact Microstrip Resonator Cell Band-pass Filter using LTCC Technology	437
<i>Sheng-Chuan Chan, Hsien-Chin Chiu, Kuo-Sheng Chin, Jeffrey S. Fu</i>	
Design of High Directivity Microchip Coupler with Single Slot Coupled Edges for GSM Dual Band.....	441
<i>S. Maheswari, T. Jayanthi</i>	
The Time-domain Calculation for the Interaction Section of Helix TWT	444
<i>Tao Liu, Pu-kun Liu, Zi-cheng Wang</i>	
Improved Efficiency of Organic Photovoltaic MEH-PPV/PCBM Device with CuPc-doping	447
<i>W. B. Chen, M. Z. Deng, H. J. Zou, C. Y. Li, L. F. Deng, P. T. Lai</i>	
Analysis and Optimization of HV ESD Protection.....	451
<i>S. J. Wang, F. Yao, B. Qin, X. Wang, H. Zhao, Q. Fang, L. Lin, A. Wang</i>	
Analysis of LDMOS-SCR ESD Protection Device for 60V SOI BCD Technology.....	455
<i>Peng Zhang, Yuan Wang, Song Jia, Xing Zhang</i>	
Validity of Modal Expansion Method for the Optical Waveguide with PML	459
<i>Jianxin Zhu, Zengsi Chen</i>	
A Subthreshold SRAM Cell Tolerant to Random Dopant Fluctuations	463
<i>Amir Reza Ahmadi Mehr, Iman Madadi, Ali Afzali-Kusha</i>	
Design for Improved NBTI Reliability of CMOS Digital IC.....	467
<i>Liu Lining, Li Bin, Zhao Mingjian, Xie Jiang</i>	
Progress on Distributed Resistance Model for pHEMT	471
<i>Hong Yin, Cejun Wei, Yu Zhu, Alex Klimashov, Cindy Zhang, Dylan Bartle</i>	
Extraction of Gate Oxide Quality and Its Correlation to the Electrical Parameters of Mos Devices.....	475
<i>R. Ortega, J. Molina, A. Torres, M. Landa, P. Alarcón, M. Escobar</i>	
Electrical Characterization of Self-aligned Titanium Silicide SBDs Formed by Furnace Annealing.....	479
<i>Elena Barbarini, Sergio Ferrero, Candido F. Pirri</i>	
A Novel Approach to Simulate Fin-width Line Edge Roughness Effect of FinFET Performance.....	483
<i>Xinjie Guo, Shaodi Wang, Chenyue Ma, Chenfei Zhang, Xinnan Lin, Wen Wu, Frank He, Wenping Wang, Zhiwei Liu, Wei Zhao, Shengqi Yang</i>	
RF Parameter Extraction of Bulk FinFET: A Non Quasi Static Approach	487
<i>Atanu Kundu, Binit Syamal, Kalyan Koley, C. K. Sarkar, N. Mohankumar</i>	
Ballistic Transport and Terahertz Electronics.....	491
<i>Michael Shur</i>	
Electrostatic Discharge (ESD): A Spoiler to Development of Next-Generation Technologies?	498
<i>Juin J. Liou</i>	